

AMENDMENT AND RESPONSE

Serial Number: 09/253,611

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Title: SELECTIVE DEPOSITION OF SOLDER BALL CONTACTS

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Sub B3
12. (Amended) A method of forming a solder ball contact, comprising:
forming a metal contact pad on a substrate;
forming an insulating layer on the metal contact pad;
removing a portion of the insulating layer to expose a portion of the metal contact pad, thereby forming an exposed portion of the metal contact pad, the exposed portion having a predetermined diameter;
adsorbing reactants on the exposed portion of the metal contact pad;
reacting the reactants on the exposed portion of the metal contact pad, thereby forming a solder contact; and
annealing the solder contact to form a solder ball contact.

A2
13. (Amended) A method of forming a solder ball contact, comprising:
forming a metal contact pad on a substrate;
forming an insulating layer on the metal contact pad;
forming a resist layer on the insulating layer;
patterning the resist layer to define a future exposed portion of the metal contact pad;
removing a portion of the insulating layer to expose a portion of the metal contact pad, thereby forming the exposed portion of the metal contact pad, the exposed portion having a predetermined diameter;
electrolytically depositing solder on the exposed portion of the metal contact pad, thereby forming a solder contact;
removing the resist layer, thereby exposing the solder contact above a surface of the insulating layer; and
annealing the solder contact to form a solder ball contact.

Sub B4
A3
Cont
16. (Amended) A method of forming a solder ball contact, comprising:
forming a metal contact pad on a substrate;
forming an insulating layer on the metal contact pad;
forming a resist layer on the insulating layer;
patterning the resist layer to define a future exposed portion of the metal contact pad;